



DMTH6009LPS

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Tc = +25°С
60V	10mΩ @ V _{GS} = 10V	89.5A
007	12mΩ @ V _{GS} = 4.5V	81.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- High-frequency switching
- Synchronous rectifications
- DC-DC converters

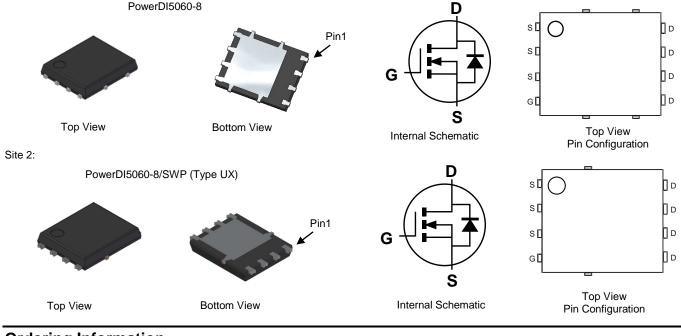
Site 1:

Features

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production-Ensures More Reliable and Robust End Application
- Low RDS(ON)-Minimizes Power Losses
- Low Q_G—Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
- https://www.diodes.com/quality/product-definitions/
- An automotive-compliant part is available under separate datasheet (DMTH6009LPSQ)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208(23)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMTH6009LPS-13	PowerDI5060-8	2500	Tape & Reel	
DMTH6009LPS-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

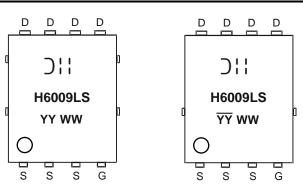
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



) | | = Manufacturer's Code Marking H6009LS = Product Type Marking Code YYWW = Date Code Marking YY or \overrightarrow{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		Vdss	60	V
Gate-Source Voltage		Vgss	±16	V
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +100°C	ID	11.76 8.3	A
Continuous Drain Current (Note 6)	Tc = +25°C T _C = +100°C	ID	89.5 63.3	А
Maximum Continuous Body Diode Forward Current (Note 6)	ls	89	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	350	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	350	A
Avalanche Current, L = 0.1mH		las	20.3	А
Avalanche Energy, L = 0.1mH		E _{AS}	20.6	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



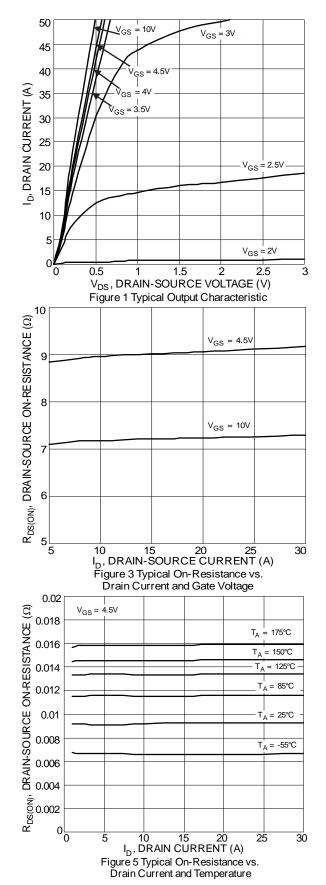
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

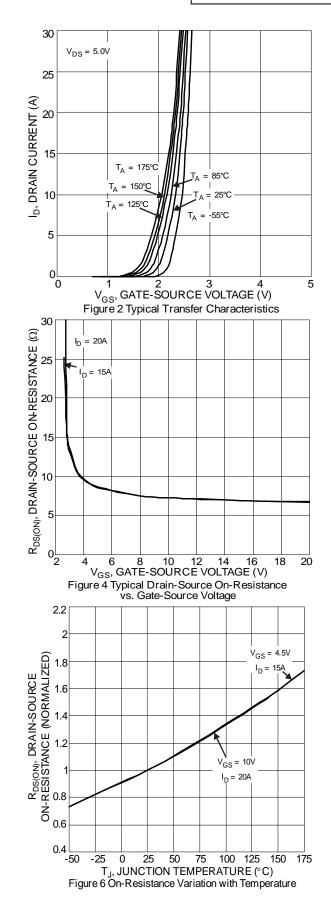
			_			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)		0			-	
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.7	—	2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Deserve	_	7.2	10	mΩ	VGS = 10V, ID = 20A
Static Drain-Source On-Resistance	RDS(ON)	—	8.9	12	111122	$V_{GS} = 4.5V, I_D = 15A$
Diode Forward Voltage	Vsd	—	0.9	_	V	VGS = 0V, IS = 20A
DYNAMIC CHARACTERISTICS (Note 8)						·
Input Capacitance	Ciss	—	1925	_	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	—	438	_		
Reverse Transfer Capacitance	Crss	—	41	_		
Gate Resistance	Rg	_	1.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	—	33.5	_		V _{DS} = 30V, I _D = 13.5A
Total Gate Charge ($V_{GS} = 4.5V$)	Qg	_	15.6	_	nC	
Gate-Source Charge	Qgs	—	4.7	_	nc	
Gate-Drain Charge	Qgd	_	5.3			
Turn-On Delay Time	tD(ON)	—	4.5	—		
Turn-On Rise Time	t _R	_	8.6			$\label{eq:VDD} \begin{array}{l} V_{DD} = 30V, \ V_{GS} = 10V, \\ R_{G} = 6\Omega, \ I_{D} = 13.5A \end{array}$
Turn-Off Delay Time	tD(OFF)		35.9	—	ns	
Turn-Off Fall Time	tF	_	15.7	—		
Body Diode Reverse Recovery Time	trr		18.2		ns	
Body Diode Reverse Recovery Charge	Qrr	_	33.1	—	nC	I _F = 13.5A, di/dt = 400A/µs

 Notes:
 7. Short duration pulse test used to minimize self-heating effect.

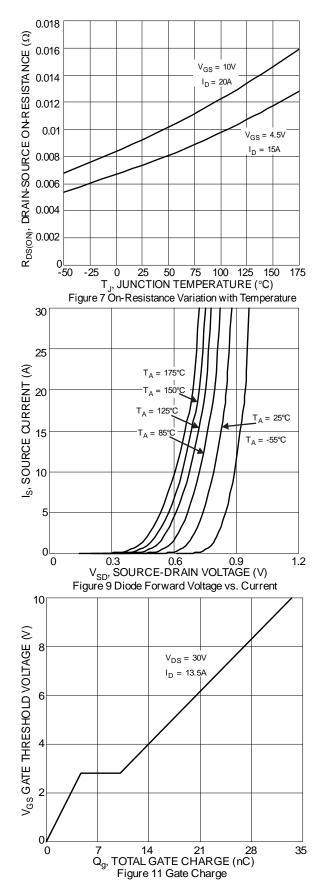
 8. Guaranteed by design. Not subject to product testing.

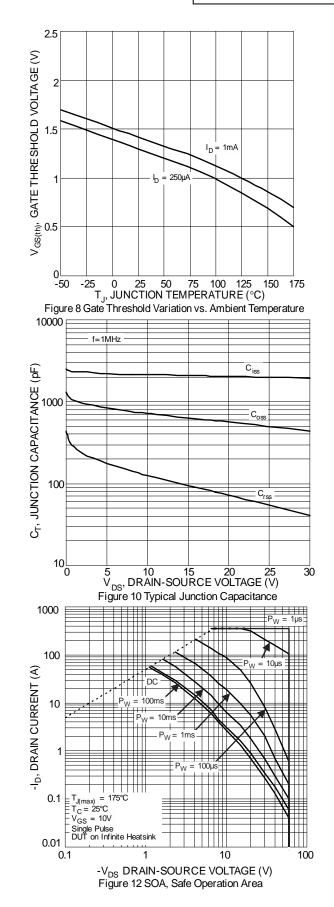






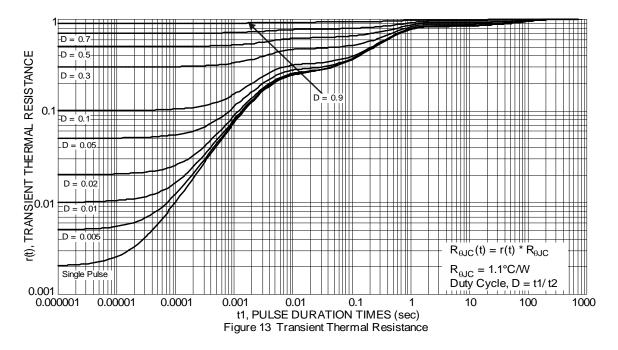






DMTH6009LPS Document number: DS38368 Rev. 4 - 2



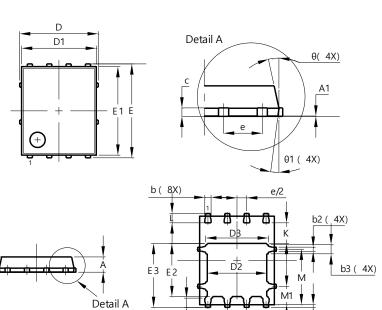




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

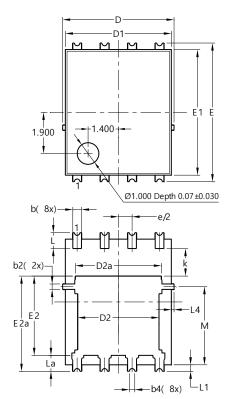
Site 1:



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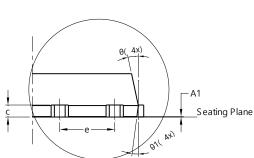
PowerDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
c	0.230	0.330	0.277	
D		5.15 BSC	;	
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
ш	(6.15 BSC	,	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е		1.27 BSC	;	
G	0.51	0.71	0.61	
ĸ	0.51	_	_	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
М	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
Al	All Dimensions in mm			

Site 2:

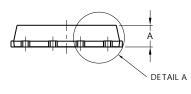


PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



DETAIL A



PowerDI5060-8/SWP (Type UX)			
Dim	Min Max Typ		
Α	0.90	1.10	1.00
A1	0	0.05	
b	0.30	0.50	0.41
b2	0.20	0.35	0.25
b4	().25REF	
c	0.230	0.330	0.277
D	5	.15 BS0	C
D1	4.70	5.10	4.90
D2	3.56	3.96	3.76
D2a	3.78	4.18	3.98
ш	6	.40 BS0	2
E1	5.60	6.00	5.80
E2	3.46	3.86	3.66
E2a	4.195	4.595	4.395
е	1	.27BSC)
k	1.05		
L	0.635	0.835	0.735
La	0.635	0.835	0.735
L1	0.200	0.400	0.300
L1a	0	.050RE	
L4	0.025	0.225	0.125
М	3.205	4.005	3.605
θ	10°	12°	11°
θ1	6°	8°	7°
All	Dimensi	ions in	mm

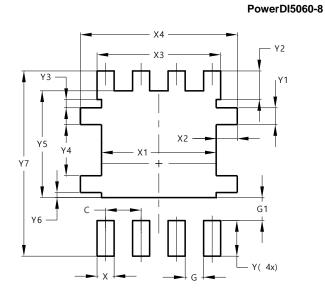
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Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

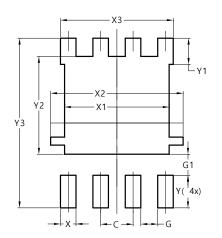
Site 1:



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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